

FAN7021

CMOS Power Amplifier

Features

- Continuous average power is 1.0W (8 Ω)
- Low THD: under 0.2% (5V)
- Do not need output coupling capacitor or bootstrap capacitor
- Low shutdown current: 0.01μA
- Shutdown: High active
- Built in reduction circuit for popping noise
- · Built in TSD circuit

Typical Applications

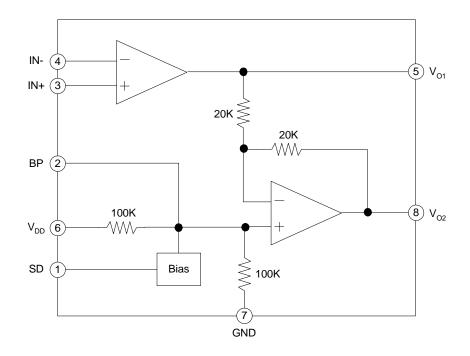
- · Cellular phone
- · Portable computer
- · Audio systems

Description

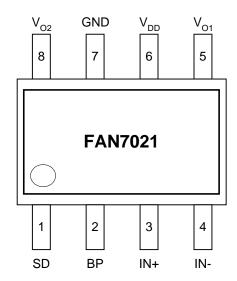
The FAN7021 is a bridge connected audio power amplifier capable of delivering 1W of continuous average power to an 8Ω load with less than 0.2% (THD) from a 5V power supply. The FAN7021 require few external components and operate on low supply voltage from 2.0V to 5.5V. Since the FAN7021 does not require output coupling capacitor, bootstrap capacitors, or snubber networks, it is ideally suited for low power portable systems that require minimum volume and weight. The FAN7021 feqtures an externally controlled, low power consumption shutdown mode (0.01 uA,typ). Additional FAN7021 features include thermal shutdown protection, unity gain stability, and external gain set.



Internal Block Diagram



Pin Assignments



Pin Definitions

Pin Number	Pin Name	Pin Function Description	
1	SD	Shutdown	
2	BP	Bypass	
3	IN+	Input +	
4	IN-	Input –	
5	Vo ₁	Power AMP output 1	
6	VDD	Supply Voltage	
7	GND	Ground	
8	VO2	Power AMP output 2	

Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Value	Unit	Remark
Maximum Supply Voltage	VDD	6.0	V	Maximum supply voltage
Power Dissipation	PD	-	W	-
Operating Temperature	TOPR	−40 ~ + 85	°C	Operating temperature
Storage Temperature	TSTG	−65 ~ + 150	°C	Storage temperature

Recommended Operating Conditions (Ta = 25°C)

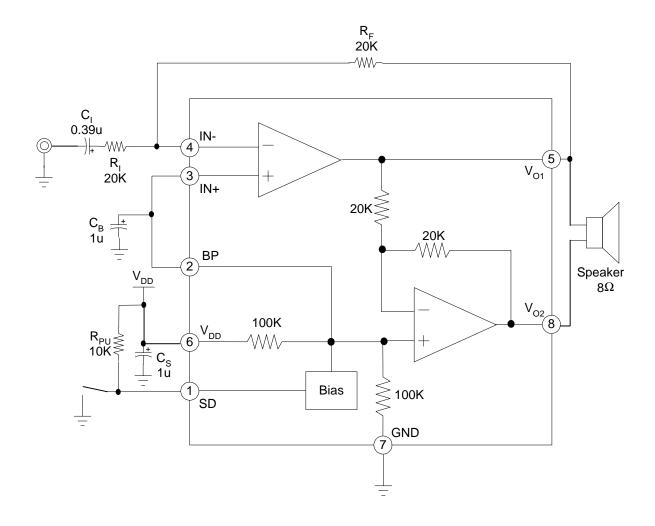
Parameter	Symbol	Min.	Тур.	Max.	Unit
Operating Supply Voltage	VDD	2.0	-	5.5	V

Electrical Characteristics

(RL = 8Ω , Ta = 25°C, Unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
V _{DD} = 5.0V, UNLESS OTHERWISE SPECIFIED						
Quiescent power supply current	IDD	DD VIN=0V,IO=0A		4.0	7.0	mA
Shutdown current	ISD	V _{SD} =V _{DD}	-	0.01	2.0	μΑ
Output offset voltage	Vos	VIN=0V	-	5	50	mV
Output power	Ро	THD=0.2% (Max.);f=1KHz	-	1	-	W
	THD+N	P _O =0.25Wrms,A _{VD} =2,filter=80KHz				
Total harmonic distortion+Noise		f=1KHz	-	0.1	-	%
		f=20KHz	-	0.4	-	%
Power supply rejection ratio	PSRR	V _{DD} =4.9V to 5.1V	-	65	-	dB
V _{DD} = 3.3V, UNLESS OTHERWISE SPECIFIED						
Quiescent power supply current	IDD	VIN=0V,IO=0A	-	3.0	-	mA
Shutdown current ISD		V _{SD} =V _{DD}	-	0.01	-	μΑ
Output offset voltage	Vos	VIN=0V	-	5	-	mV
Output power	Ро	THD=1% (Max.);f=1KHz	0.45	0.5	-	W
		PO=0.25Wrms,AVD=2,filter=80KHz				
Total harmonic distortion+Noise	THD+N	f=1KHz	-	0.15	-	%
		f=20KHz	-	0.45	-	%
Power supply rejection ratio	PSRR	V _{DD} =3.2V to 3.4V	-	65	-	dB
V _{DD} = 2.6V, UNLESS OTHERW	ISE SPEC	IFIED				
Quiescent power supply current	IDD	V _{IN} =0V,I _O =0A	-	2.5	-	mA
Shutdown current	ISD	V _{SD} =V _{DD}	-	0.01	-	μΑ
Output offset voltage Vos		V _{IN} =0V	-	5	-	mV
Output power	Ро	THD=0.3% (Max.);f=1KHz	-	0.25	-	W
		PO=0.25Wrms,AVD=2,filter=80KHz				
Total harmonic distortion+Noise	THD+N	f=1KHz	-	0.25	-	%
		f=20KHz	-	0.5	-	%
Power supply rejection ratio PSRF		V _{DD} =2.5V to 2.7V	-	65	-	dB

Typical Application Circuits



Performance Characteristics

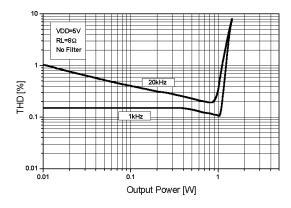


Figure 1. THD+N versus output power

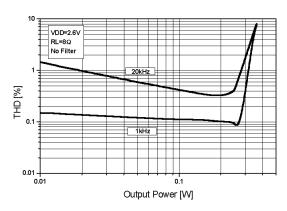


Figure 3. THD+N versus output power

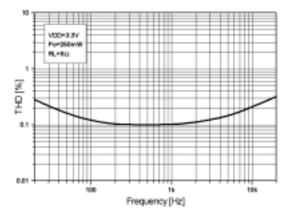


Figure 5. THD+N versus Frequency

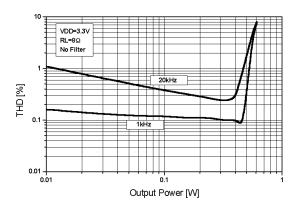


Figure 2. THD+N versus output power

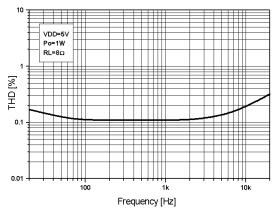


Figure 4. THD+N versus Frequency

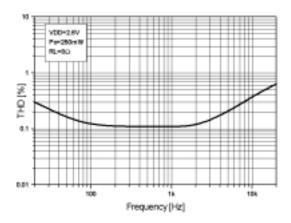


Figure 6. THD+N versus Frequency

Performance Characteristics (Continued)

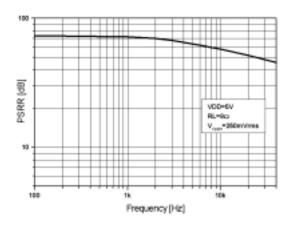


Figure 7. Power supply rejection ration

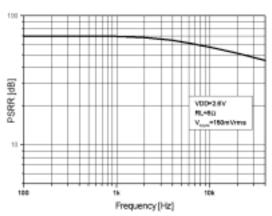


Figure 9. Power supply rejection ration

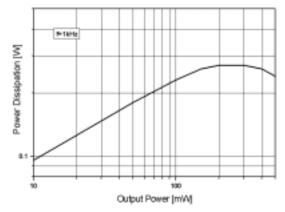


Figure 11. Power Dissipation versus output power

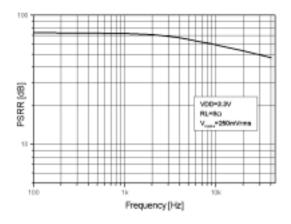


Figure 8. Power supply rejection ration

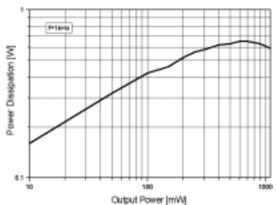


Figure 10. Power Dissipation versus output power

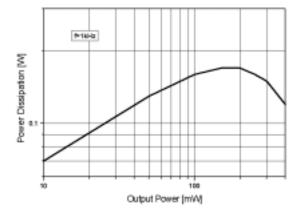
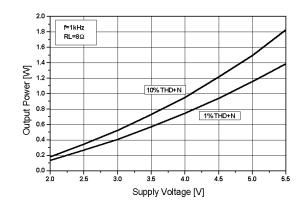


Figure 12. Power Dissipation versus output power

Performance Characteristics (Continued)





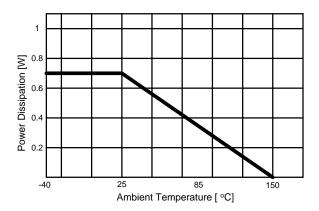
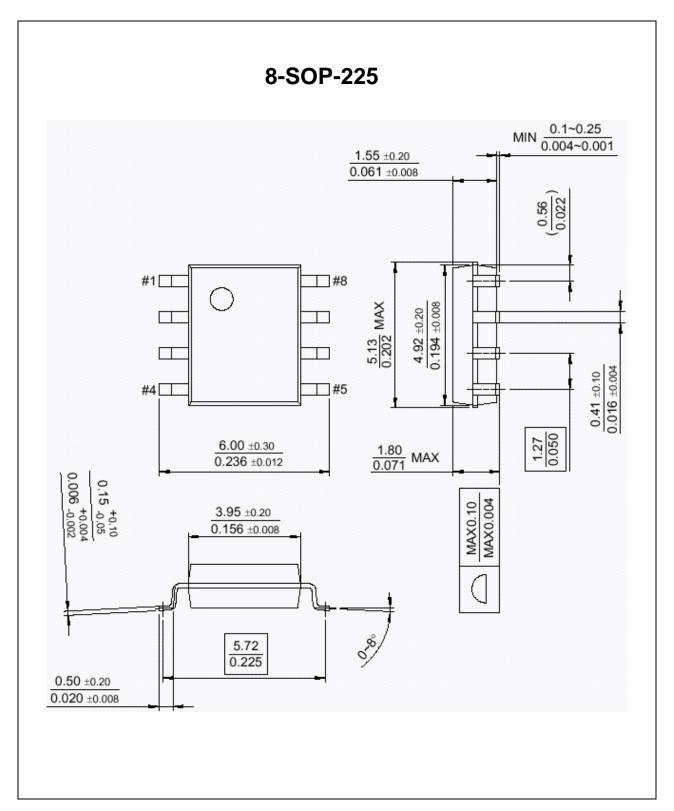


Figure 14. Power darting curve

Mechanical Dimensions (Unit: mm)

Package



Ordering Information

Device	Package	Operating Temp.
FAN7021M	8-SOP-225	−40°C ~ +85°C

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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